



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

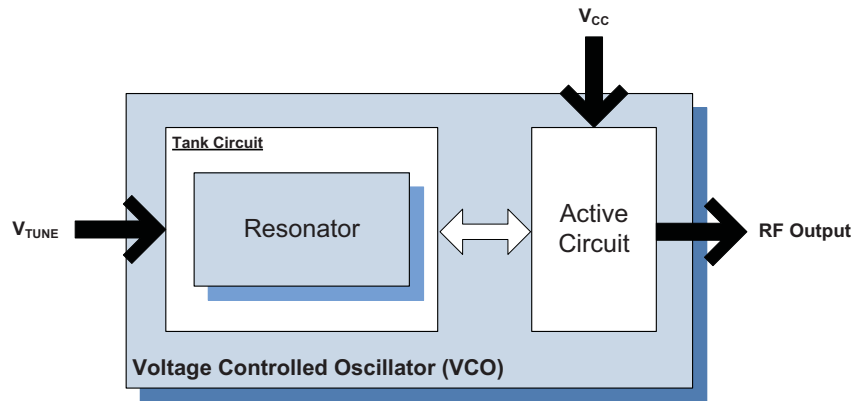
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





Features

- Ultra-linear Tuning/Ultra-low Phase Noise
- Frequency: 2220MHz to 2350MHz
- Resonator: Ceramic
- PCB: Rogers
- Package Size: 12.7mm x 12.7mm x 5.59mm (0.5in x 0.5in x 0.22in)



Functional Block Diagram

Applications

- Point-to-Point Radio
- DRO/YIG Multiplied Replacements
- Low Phase Noise Applications
- SAW VCO Replacements

Product Description

This VCO series features ultra-low phase noise, lower phase transients, lower harmonics, and lower pushing and pulling without any performance penalties typically associated with high technology designs.

Ordering Information

UMX-114-D16-G Contact us at 1-480-756-6070

Optimum Technology Matching® Applied

- | | | | |
|--------------------------------------|--------------------------------------|--|------------------------------------|
| <input type="checkbox"/> GaAs HBT | <input type="checkbox"/> SiGe BiCMOS | <input type="checkbox"/> GaAs pHEMT | <input type="checkbox"/> GaN HEMT |
| <input type="checkbox"/> GaAs MESFET | <input type="checkbox"/> Si BiCMOS | <input type="checkbox"/> Si CMOS | <input type="checkbox"/> BiFET HBT |
| <input type="checkbox"/> InGaP HBT | <input type="checkbox"/> SiGe HBT | <input checked="" type="checkbox"/> Si BJT | <input type="checkbox"/> LDMOS |

RF MICRO DEVICES®, RFMD®, Optimum Technology Matching®, Enabling Wireless Connectivity™, PowerStar®, POLARIS™ TOTAL RADIO™ and UltimateBlue™ are trademarks of RFMD, LLC. BLUETOOTH is a trademark owned by Bluetooth SIG, Inc., U.S.A. and licensed for use by RFMD. All other trade names, trademarks and registered trademarks are the property of their respective owners. ©2006, RF Micro Devices, Inc.

Absolute Maximum Ratings

Parameter	Rating	Unit
Operating Ambient Temperature[1]	-40 to +85	°C
Storage Temperature	-55 to +125	°C

[1] Frequency drift: 8MHz typical (either extreme)



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

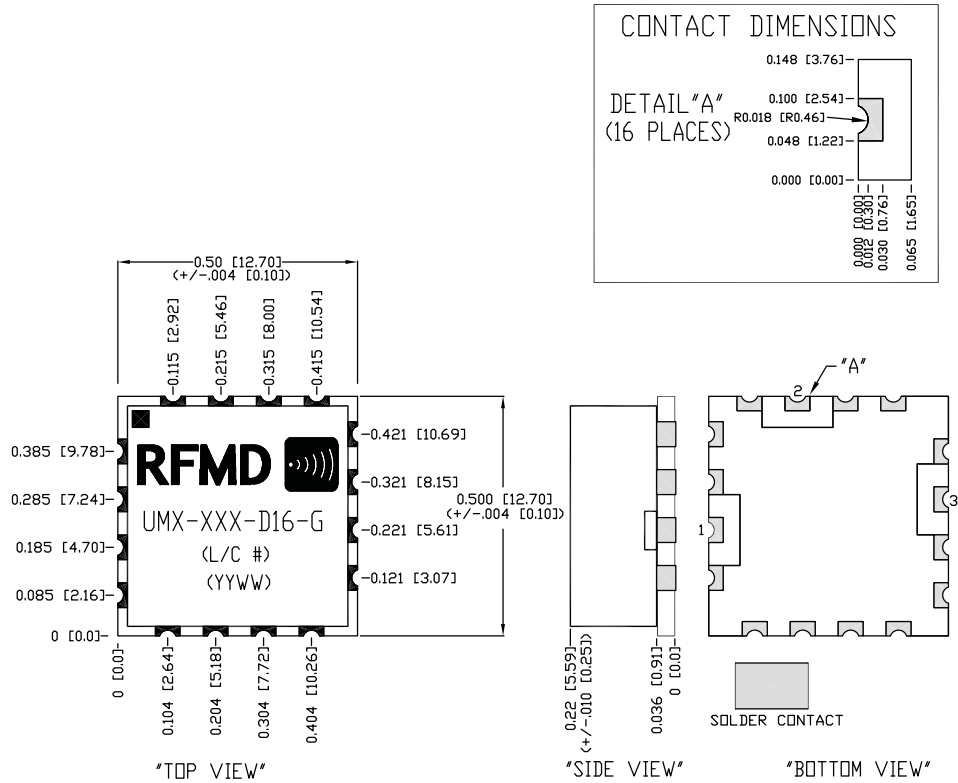


RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2002/95/EC.

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Overall					
Frequency Range	2220		2350	MHz	
Tuning Voltage	0.5		4.5	V _{DC}	
Tuning Sensitivity		47		MHz/V	
Output Power	5	7	9	dBm	
	5				At V _T = 0
Output Phase Noise		-81	-76	dBc/Hz	1kHz
		-107	-102	dBc/Hz	10kHz
		-127	-122	dBc/Hz	100kHz
		-147	-142	dBc/Hz	1000kHz
		-164	-157	dBc/Hz	10000kHz
Second Harmonic		-20	-15	dBc	
Frequency Pulling		2	3	MHz p-p	At 12dB _r , all phases
Tuning Port Capacitance		28		pF	
Modulation Bandwidth		1000		kHz	3dB BW
Frequency Pushing		1	1.5	MHz/V	
Power Supply					
Operating Voltage		5		V	
Supply Current		20		mA	

Package Drawing & Pin Outs

12.7mm x 12.7mm x 5.59mm (0.5in x 0.5in x 0.22in)



CONTACT ASSIGNMENTS:	
1:	RF OUT
2:	SUPPLY INPUT
3:	TUNING VOLTAGE INPUT
ALL OTHER CONTACTS ARE GROUND	